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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Zhenan Bao

Serial No.: 10/727,709

Filed: December 4, 2003

For: ORGANIC FIELD EFFECT TRANSISTORS WITH ACTIVE CHANNELS  
FORMED OF DENSIFIED LAYERS

Group No.: 2811

Examiner: Douglas A. Wille

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Alexandria, VA 22313, on

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Marty Ballo  
(Printed or typed name of person signing the certificate)

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(Signature of the person signing the certificate)

3-13-03  
(Date of Signature)

Sir:

INFORMATION DISCLOSURE STATEMENT

In accordance with 37 C.F.R. §1.56 and the provisions of 37 C.F.R. §§1.97 and 1.98 and §609 of the Manual of Patent Examining Procedure, Applicant hereby makes a disclosure of the patents, publications and other information listed below and on the accompanying form PTO-1449, which may be potentially material to the patentability of the invention disclosed in the above-referenced application. Pursuant to § 1.97(e) the Applicant hereby states that each item of information contained in the information disclosure statement was cited in a communication from a

foreign patent office in a counterpart foreign application not more than three months prior to the filing of the information disclosure statement.

<u>Foreign Patent No.</u>	<u>Country</u>	<u>Date</u>
WO 03/056641 A	PCT	July 10, 2003
EP 1 355 323 A	EPO	October 22, 2003
EP 0 460 242 A	EPO	December 11, 1991

**Other References:**

PEARSON et al. "Field-Effect Transistor Based on Organometallic Langmuir-Blodgett Film" Electronics Letters, IEE Stevanage, GB, Volume 29, No. 15, July 22, 1993, pages 1377-1378, XP000385679, ISSN: 0013-5194.

Applicant hereby certifies that each item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the statement.

As attorney for the Applicant, I am signing below on the basis of the information supplied by an individual designated in § 1.56(c).

Respectfully submitted,

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